

# NX3L1T3157

Low-ohmic single-pole double-throw analog switch

Rev. 07 — 21 January 2010

Product data sheet

## 1. General description

The NX3L1T3157 is a low-ohmic single-pole double-throw analog switch suitable for use as an analog or digital 2:1 multiplexer/demultiplexer. It has a digital select input (S), two independent inputs/outputs (Y0 and Y1) and a common input/output (Z).

Schmitt trigger action at the digital input makes the circuit tolerant to slower input rise and fall times. Low threshold digital input allows this device to be driven by 1.8 V logic levels in 3.3 V applications without significant increase in supply current  $I_{CC}$ . The NX3L1T3157 allows signals with amplitude up to  $V_{CC}$  to be transmitted from Z to Y0 or Y1, or from Y0 or Y1 to Z. Its low ON resistance (0.5  $\Omega$ ) and flatness (0.13  $\Omega$ ) ensures minimal attenuation and distortion of transmitted signals.

## 2. Features

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
  - ◆ 1.6  $\Omega$  (typical) at  $V_{CC} = 1.4$  V
  - ◆ 1.0  $\Omega$  (typical) at  $V_{CC} = 1.65$  V
  - ◆ 0.55  $\Omega$  (typical) at  $V_{CC} = 2.3$  V
  - ◆ 0.50  $\Omega$  (typical) at  $V_{CC} = 2.7$  V
  - ◆ 0.50  $\Omega$  (typical) at  $V_{CC} = 4.3$  V
- Break-before-make switching
- High noise immunity
- ESD protection:
  - ◆ HBM JESD22-A114E Class 3A exceeds 7500 V
  - ◆ MM JESD22-A115-A exceeds 200 V
  - ◆ CDM AEC-Q100-011 revision B exceeds 1000 V
  - ◆ IEC61000-4-2 contact discharge exceeds 8000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level A
- 1.8 V control logic at  $V_{CC} = 3.6$  V
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below  $V_{CC}$
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from  $-40$  °C to  $+85$  °C and from  $-40$  °C to  $+125$  °C

### 3. Applications

- Cell phone
- PDA
- Portable media player

### 4. Ordering information

**Table 1. Ordering information**

Type number	Package				Version
	Temperature range	Name	Description		
NX3L1T3157GW	-40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads		SOT363
NX3L1T3157GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm		SOT886

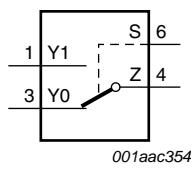
### 5. Marking

**Table 2. Marking codes<sup>[1]</sup>**

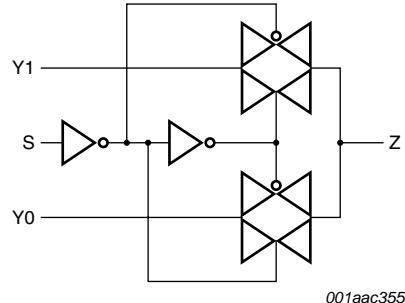
Type number	Marking code
NX3L1T3157GW	MI
NX3L1T3157GM	MI

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

### 6. Functional diagram



**Fig 1. Logic symbol**



**Fig 2. Logic diagram**

## 7. Pinning information

### 7.1 Pinning

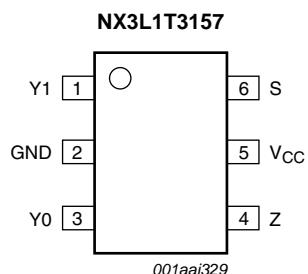


Fig 3. Pin configuration SOT363 (SC-88)

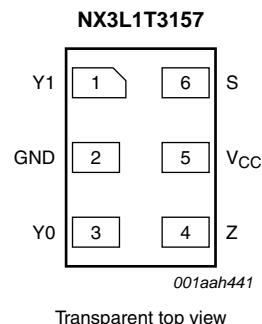


Fig 4. Pin configuration SOT886 (XSON6)

### 7.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
Y1	1	independent input or output
GND	2	ground (0 V)
Y0	3	independent input or output
Z	4	common output or input
V <sub>CC</sub>	5	supply voltage
S	6	select input

## 8. Functional description

Table 4. Function table<sup>[1]</sup>

Input S	Channel on
L	Y0
H	Y1

[1] H = HIGH voltage level; L = LOW voltage level.

## 9. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
V <sub>I</sub>	input voltage	select input S	[1] -0.5	+4.6	V
V <sub>SW</sub>	switch voltage		[2] -0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < -0.5 V	-50	-	mA
I <sub>SK</sub>	switch clamping current	V <sub>I</sub> < -0.5 V or V <sub>I</sub> > V <sub>CC</sub> + 0.5 V	-	±50	mA
I <sub>SW</sub>	switch current	V <sub>SW</sub> > -0.5 V or V <sub>SW</sub> < V <sub>CC</sub> + 0.5 V; source or sink current	-	±350	mA
		V <sub>SW</sub> > -0.5 V or V <sub>SW</sub> < V <sub>CC</sub> + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C	[3] -	250	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] For SC-88 package: above 87.5 °C the value of P<sub>tot</sub> derates linearly with 4.0 mW/K.

For XSON6 package: above 118 °C the value of P<sub>tot</sub> derates linearly with 7.8 mW/K.

## 10. Recommended operating conditions

**Table 6. Recommended operating conditions**

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		1.4	4.3	V
V <sub>I</sub>	input voltage	select input S	0	4.3	V
V <sub>SW</sub>	switch voltage		[1] 0	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 1.4 V to 4.3 V	[2] -	200	ns/V

[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Yn. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

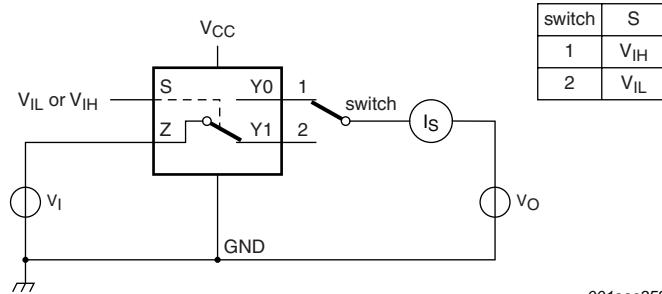
## 11. Static characteristics

**Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

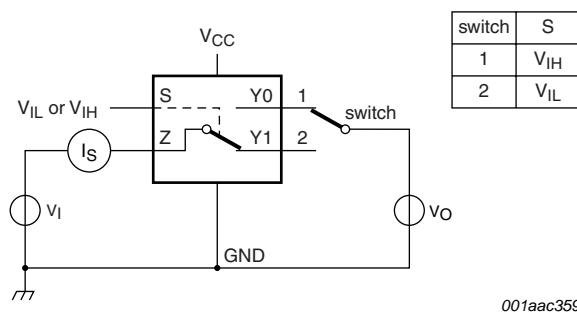
Symbol	Parameter	Conditions	$T_{amb} = 25\text{ }^{\circ}\text{C}$			$T_{amb} = -40\text{ }^{\circ}\text{C to }+125\text{ }^{\circ}\text{C}$			Unit
			Min	Typ	Max	Min	Max (85 °C)	Max (125 °C)	
$V_{IH}$	HIGH-level input voltage	$V_{CC} = 1.4\text{ V to }1.6\text{ V}$	0.9	-	-	0.9	-	-	V
		$V_{CC} = 1.65\text{ V to }1.95\text{ V}$	0.9	-	-	0.9	-	-	V
		$V_{CC} = 2.3\text{ V to }2.7\text{ V}$	1.1	-	-	1.1	-	-	V
		$V_{CC} = 2.7\text{ V to }3.6\text{ V}$	1.3	-	-	1.3	-	-	V
		$V_{CC} = 3.6\text{ V to }4.3\text{ V}$	1.4	-	-	1.4	-	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 1.4\text{ V to }1.6\text{ V}$	-	-	0.3	-	0.3	0.3	V
		$V_{CC} = 1.65\text{ V to }1.95\text{ V}$	-	-	0.4	-	0.4	0.3	V
		$V_{CC} = 2.3\text{ V to }2.7\text{ V}$	-	-	0.4	-	0.4	0.4	V
		$V_{CC} = 2.7\text{ V to }3.6\text{ V}$	-	-	0.5	-	0.5	0.5	V
		$V_{CC} = 3.6\text{ V to }4.3\text{ V}$	-	-	0.6	-	0.6	0.6	V
$I_I$	input leakage current	select input S; $V_I = \text{GND to }4.3\text{ V};$ $V_{CC} = 1.4\text{ V to }4.3\text{ V}$	-	-	-	-	$\pm 0.5$	$\pm 1$	$\mu\text{A}$
$I_{S(OFF)}$	OFF-state leakage current	Y0 and Y1 port; see <a href="#">Figure 5</a>	-	-	$\pm 5$	-	$\pm 50$	$\pm 500$	nA
		$V_{CC} = 1.4\text{ V to }3.6\text{ V}$	-	-	$\pm 10$	-	$\pm 50$	$\pm 500$	nA
$I_{S(ON)}$	ON-state leakage current	Z port; see <a href="#">Figure 6</a>	-	-	$\pm 5$	-	$\pm 50$	$\pm 500$	nA
		$V_{CC} = 1.4\text{ V to }3.6\text{ V}$	-	-	$\pm 10$	-	$\pm 50$	$\pm 500$	nA
$I_{CC}$	supply current	$V_I = V_{CC}$ or GND; $V_{SW} = \text{GND or }V_{CC}$	-	-	100	-	690	6000	nA
		$V_{CC} = 3.6\text{ V}$	-	-	150	-	800	7000	nA
		$V_{CC} = 4.3\text{ V}$	-	-	-	-	-	-	-
$\Delta I_{CC}$	additional supply current	$V_{SW} = \text{GND or }V_{CC}$	-	-	-	-	-	-	-
		$V_I = 2.6\text{ V}; V_{CC} = 4.3\text{ V}$	-	2.0	4.0	-	7	7	$\mu\text{A}$
		$V_I = 2.6\text{ V}; V_{CC} = 3.6\text{ V}$	-	0.35	0.7	-	1	1	$\mu\text{A}$
		$V_I = 1.8\text{ V}; V_{CC} = 4.3\text{ V}$	-	7.0	10.0	-	15	15	$\mu\text{A}$
		$V_I = 1.8\text{ V}; V_{CC} = 3.6\text{ V}$	-	2.5	4.0	-	5	5	$\mu\text{A}$
		$V_I = 1.8\text{ V}; V_{CC} = 2.5\text{ V}$	-	50	200	-	300	500	nA
$C_I$	input capacitance	-	1.0	-	-	-	-	-	pF
$C_{S(OFF)}$	OFF-state capacitance	-	35	-	-	-	-	-	pF
$C_{S(ON)}$	ON-state capacitance	-	130	-	-	-	-	-	pF

### 11.1 Test circuits



$V_I = 0.3 \text{ V or } V_{CC} - 0.3 \text{ V}; V_O = V_{CC} - 0.3 \text{ V or } 0.3 \text{ V.}$

Fig 5. Test circuit for measuring OFF-state leakage current



$V_I = 0.3 \text{ V or } V_{CC} - 0.3 \text{ V}; V_O = V_{CC} - 0.3 \text{ V or } 0.3 \text{ V.}$

Fig 6. Test circuit for measuring ON-state leakage current

## 11.2 ON resistance

**Table 8. ON resistance**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see [Figure 8](#) to [Figure 14](#).

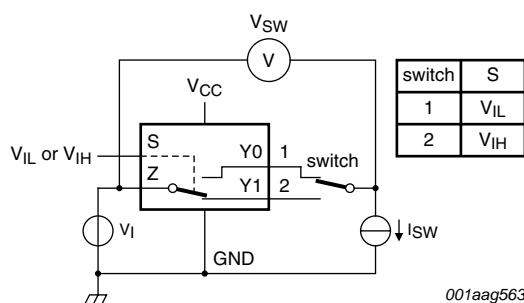
Symbol	Parameter	Conditions	$T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$			$T_{amb} = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$		Unit
			Min	Typ <sup>[1]</sup>	Max	Min	Max	
$R_{ON(peak)}$	ON resistance (peak)	$V_I = \text{GND to } V_{CC}$ ; $I_{SW} = 100 \text{ mA}$ ; see <a href="#">Figure 7</a>	$V_{CC} = 1.4 \text{ V}$	-	1.6	3.7	-	4.1 $\Omega$
			$V_{CC} = 1.65 \text{ V}$	-	1.0	1.6	-	1.7 $\Omega$
			$V_{CC} = 2.3 \text{ V}$	-	0.55	0.8	-	0.9 $\Omega$
			$V_{CC} = 2.7 \text{ V}$	-	0.5	0.75	-	0.9 $\Omega$
			$V_{CC} = 4.3 \text{ V}$	-	0.5	0.75	-	0.9 $\Omega$
$\Delta R_{ON}$	ON resistance mismatch between channels	$V_I = \text{GND to } V_{CC}$ ; $I_{SW} = 100 \text{ mA}$	<a href="#">[2]</a>					
			$V_{CC} = 1.4 \text{ V}$	-	0.04	0.3	-	0.3 $\Omega$
			$V_{CC} = 1.65 \text{ V}$	-	0.04	0.2	-	0.3 $\Omega$
			$V_{CC} = 2.3 \text{ V}$	-	0.02	0.08	-	0.1 $\Omega$
			$V_{CC} = 2.7 \text{ V}$	-	0.02	0.075	-	0.1 $\Omega$
$R_{ON(flat)}$	ON resistance (flatness)	$V_I = \text{GND to } V_{CC}$ ; $I_{SW} = 100 \text{ mA}$	<a href="#">[3]</a>					
			$V_{CC} = 1.4 \text{ V}$	-	1.0	3.3	-	3.6 $\Omega$
			$V_{CC} = 1.65 \text{ V}$	-	0.5	1.2	-	1.3 $\Omega$
			$V_{CC} = 2.3 \text{ V}$	-	0.15	0.3	-	0.35 $\Omega$
			$V_{CC} = 2.7 \text{ V}$	-	0.13	0.3	-	0.35 $\Omega$
			$V_{CC} = 4.3 \text{ V}$	-	0.2	0.4	-	0.45 $\Omega$

[1] Typical values are measured at  $T_{amb} = 25^{\circ}\text{C}$ .

[2] Measured at identical  $V_{CC}$ , temperature and input voltage.

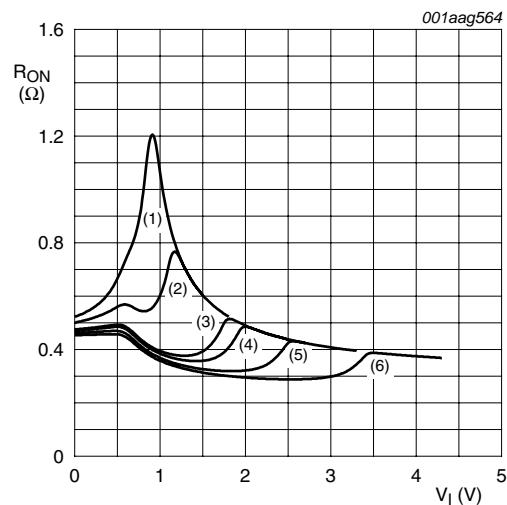
[3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical  $V_{CC}$  and temperature.

### 11.3 ON resistance test circuit and graphs



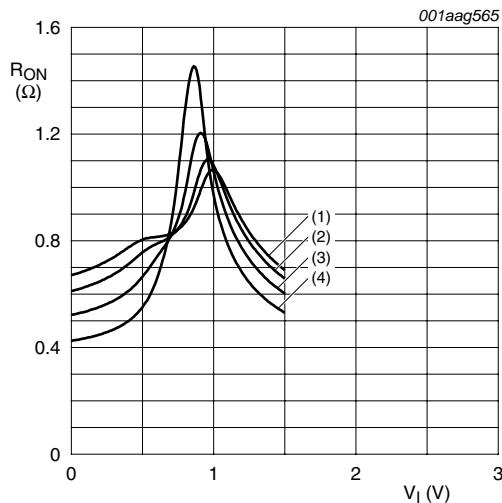
$$R_{ON} = V_{SW} / I_{SW}.$$

Fig 7. Test circuit for measuring ON resistance

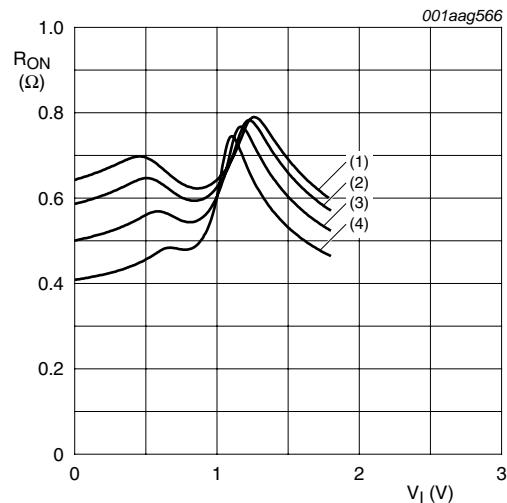


(1)  $V_{CC} = 1.5$  V.  
 (2)  $V_{CC} = 1.8$  V.  
 (3)  $V_{CC} = 2.5$  V.  
 (4)  $V_{CC} = 2.7$  V.  
 (5)  $V_{CC} = 3.3$  V.  
 (6)  $V_{CC} = 4.3$  V.  
 Measured at  $T_{amb} = 25$  °C.

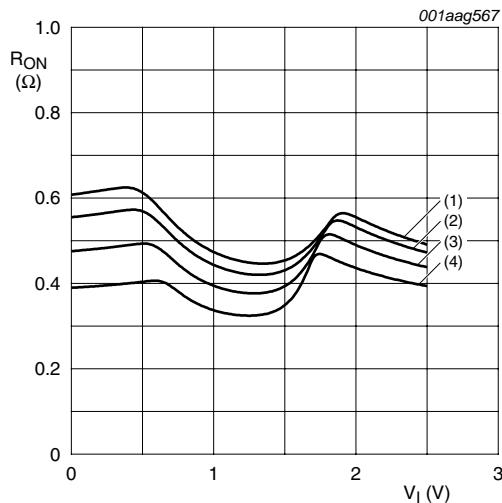
Fig 8. Typical ON resistance as a function of input voltage



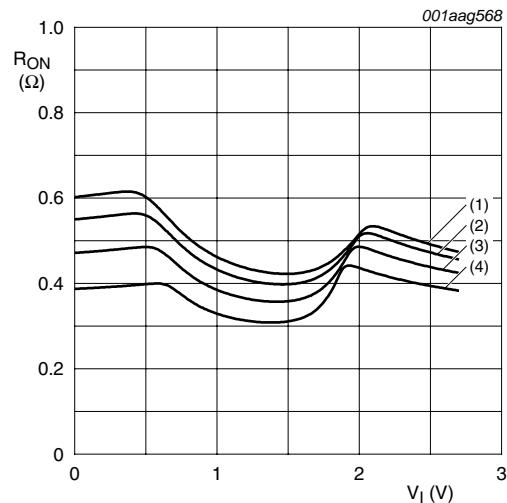
**Fig 9.** ON resistance as a function of input voltage;  
 $V_{CC} = 1.5\text{ V}$



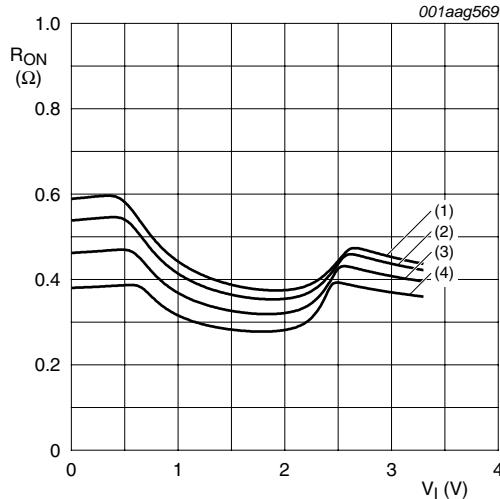
**Fig 10.** ON resistance as a function of input voltage;  
 $V_{CC} = 1.8\text{ V}$



**Fig 11.** ON resistance as a function of input voltage;  
 $V_{CC} = 2.5\text{ V}$

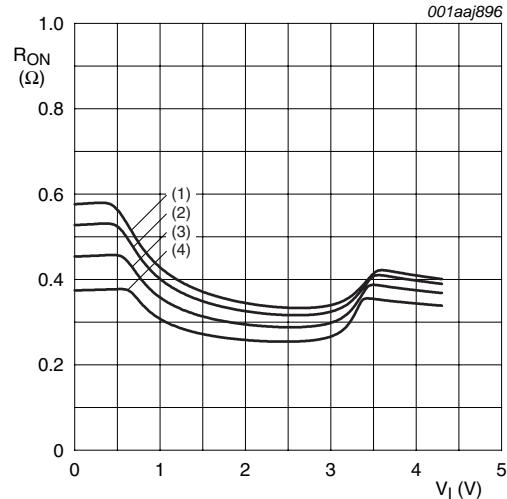


**Fig 12.** ON resistance as a function of input voltage;  
 $V_{CC} = 2.7\text{ V}$



- (1)  $T_{amb} = 125$  °C.
- (2)  $T_{amb} = 85$  °C.
- (3)  $T_{amb} = 25$  °C.
- (4)  $T_{amb} = -40$  °C.

**Fig 13. ON resistance as a function of input voltage;  $V_{CC} = 3.3$  V**



- (1)  $T_{amb} = 125$  °C.
- (2)  $T_{amb} = 85$  °C.
- (3)  $T_{amb} = 25$  °C.
- (4)  $T_{amb} = -40$  °C.

**Fig 14. ON resistance as a function of input voltage;  $V_{CC} = 4.3$  V**

## 12. Dynamic characteristics

**Table 9. Dynamic characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see [Figure 17](#).

Symbol	Parameter	Conditions	25 °C			−40 °C to +125 °C			Unit
			Min	Typ <sup>[1]</sup>	Max	Min	Max (85 °C)	Max (125 °C)	
$t_{en}$	enable time	S to Z or Yn; see <a href="#">Figure 15</a>							
		$V_{CC} = 1.4$ V to 1.6 V	-	50	90	-	120	120	ns
		$V_{CC} = 1.65$ V to 1.95 V	-	36	70	-	80	90	ns
		$V_{CC} = 2.3$ V to 2.7 V	-	24	45	-	50	55	ns
		$V_{CC} = 2.7$ V to 3.6 V	-	22	40	-	45	50	ns
		$V_{CC} = 3.6$ V to 4.3 V	-	22	40	-	45	50	ns
$t_{dis}$	disable time	S to Z or Yn; see <a href="#">Figure 15</a>							
		$V_{CC} = 1.4$ V to 1.6 V	-	32	70	-	80	90	ns
		$V_{CC} = 1.65$ V to 1.95 V	-	20	55	-	60	65	ns
		$V_{CC} = 2.3$ V to 2.7 V	-	12	25	-	30	35	ns
		$V_{CC} = 2.7$ V to 3.6 V	-	10	20	-	25	30	ns
		$V_{CC} = 3.6$ V to 4.3 V	-	10	20	-	25	30	ns

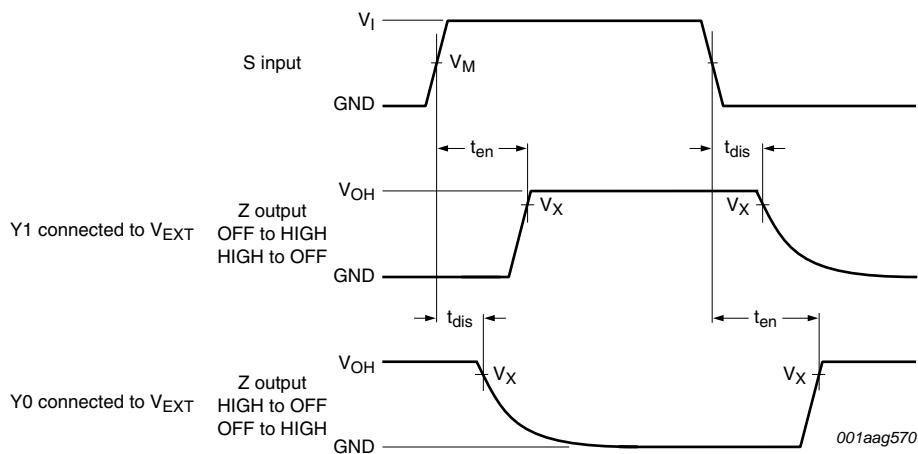
**Table 9. Dynamic characteristics ...continued**At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see [Figure 17](#).

Symbol	Parameter	Conditions	25 °C			−40 °C to +125 °C			Unit
			Min	Typ <sup>[1]</sup>	Max	Min	Max (85 °C)	Max (125 °C)	
t <sub>b-m</sub>	break-before-make time	see <a href="#">Figure 16</a> <sup>[2]</sup>							ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	19	-	9	-	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	17	-	7	-	-	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	13	-	4	-	-	ns
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	10	-	3	-	-	ns
		V <sub>CC</sub> = 3.6 V to 4.3 V	-	10	-	2	-	-	ns

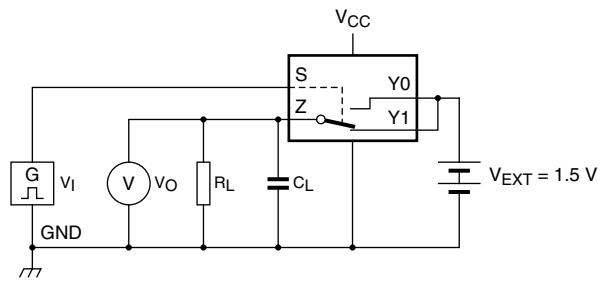
[1] Typical values are measured at T<sub>amb</sub> = 25 °C and V<sub>CC</sub> = 1.5 V, 1.8 V, 2.5 V, 3.3 and 4.3 V respectively.

[2] Break-before-make guaranteed by design.

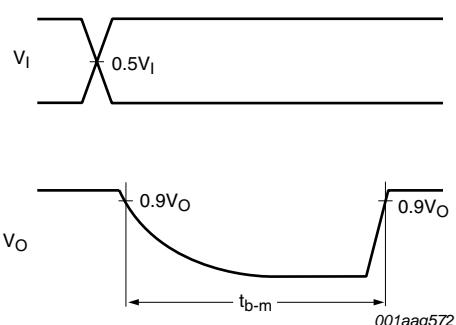
## 12.1 Waveform and test circuits

Measurement points are given in [Table 10](#).Logic level: V<sub>OH</sub> is typical output voltage level that occurs with the output load.**Fig 15. Enable and disable times****Table 10. Measurement points**

Supply voltage	Input	Output
V <sub>CC</sub>	V <sub>M</sub>	V <sub>X</sub>
1.4 V to 4.3 V	0.5V <sub>CC</sub>	0.9V <sub>OH</sub>

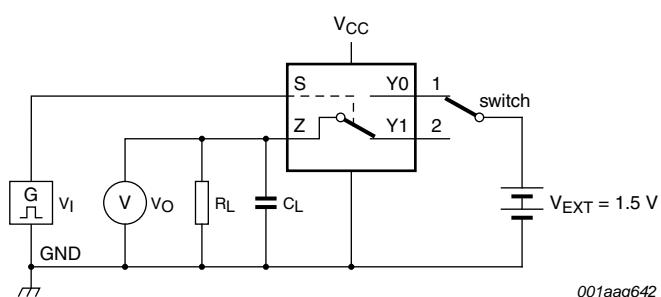


a. Test circuit



b. Input and output measurement points

Fig 16. Test circuit for measuring break-before-make timing

Test data is given in [Table 11](#).

Definitions test circuit:

 $R_L$  = Load resistance. $C_L$  = Load capacitance including jig and probe capacitance. $V_{EXT}$  = External voltage for measuring switching times.

Fig 17. Load circuit for switching times

Table 11. Test data

Supply voltage	Input	Load		
$V_{CC}$	$V_I$	$t_r, t_f$	$C_L$	$R_L$
1.4 V to 4.3 V	$V_{CC}$	$\leq 2.5 \text{ ns}$	35 pF	50 $\Omega$

## 12.2 Additional dynamic characteristics

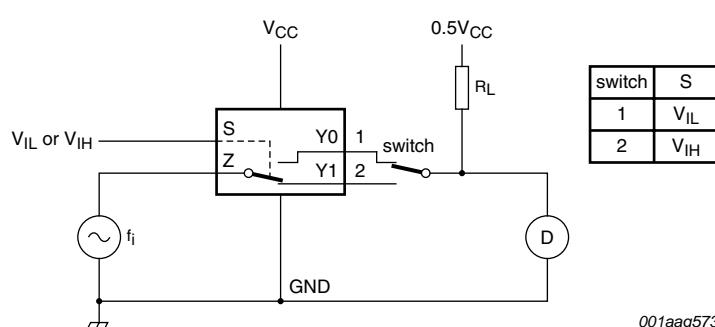
**Table 12. Additional dynamic characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $V_I = \text{GND}$  or  $V_{CC}$  (unless otherwise specified);  $t_f = t_{fI} \leq 2.5 \text{ ns}$ ;  $T_{amb} = 25^\circ\text{C}$ .

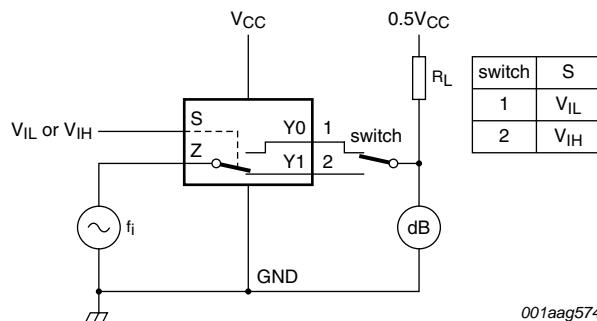
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
THD	total harmonic distortion	$f_i = 20 \text{ Hz to } 20 \text{ kHz}$ ; $R_L = 32 \Omega$ ; see <a href="#">Figure 18</a>	[1]			
		$V_{CC} = 1.4 \text{ V}$ ; $V_I = 1 \text{ V}$ (p-p)	-	0.15	-	%
		$V_{CC} = 1.65 \text{ V}$ ; $V_I = 1.2 \text{ V}$ (p-p)	-	0.10	-	%
		$V_{CC} = 2.3 \text{ V}$ ; $V_I = 1.5 \text{ V}$ (p-p)	-	0.02	-	%
		$V_{CC} = 2.7 \text{ V}$ ; $V_I = 2 \text{ V}$ (p-p)	-	0.02	-	%
		$V_{CC} = 4.3 \text{ V}$ ; $V_I = 2 \text{ V}$ (p-p)	-	0.02	-	%
$f_{(-3\text{dB})}$	-3 dB frequency response	$R_L = 50 \Omega$ ; see <a href="#">Figure 19</a>	[1]			
		$V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$	-	60	-	MHz
$\alpha_{iso}$	isolation (OFF-state)	$f_i = 100 \text{ kHz}$ ; $R_L = 50 \Omega$ ; see <a href="#">Figure 20</a>	[1]			
		$V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$	-	-90	-	dB
$V_{ct}$	crosstalk voltage	between digital inputs and switch;				
		$f_i = 1 \text{ MHz}$ ; $C_L = 50 \text{ pF}$ ; $R_L = 50 \Omega$ ; see <a href="#">Figure 21</a>				
		$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$	-	0.2	-	V
$V_{CC}$		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	0.3	-	V
$Q_{inj}$	charge injection	$f_i = 1 \text{ MHz}$ ; $C_L = 0.1 \text{ nF}$ ; $R_L = 1 \text{ M}\Omega$ ; $V_{gen} = 0 \text{ V}$ ; $R_{gen} = 0 \Omega$ ; see <a href="#">Figure 22</a>				
		$V_{CC} = 1.5 \text{ V}$	-	3	-	pC
		$V_{CC} = 1.8 \text{ V}$	-	4	-	pC
		$V_{CC} = 2.5 \text{ V}$	-	6	-	pC
		$V_{CC} = 3.3 \text{ V}$	-	9	-	pC
		$V_{CC} = 4.3 \text{ V}$	-	15	-	pC

[1]  $f_i$  is biased at  $0.5V_{CC}$ .

## 12.3 Test circuits

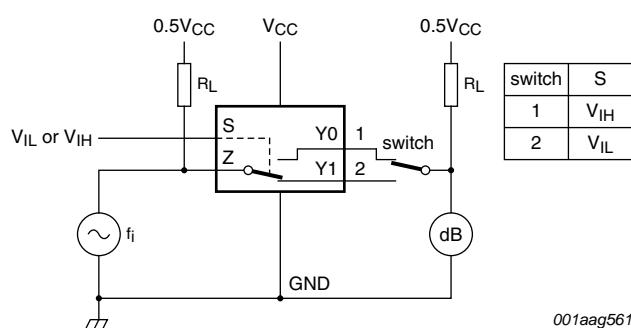


**Fig 18. Test circuit for measuring total harmonic distortion**



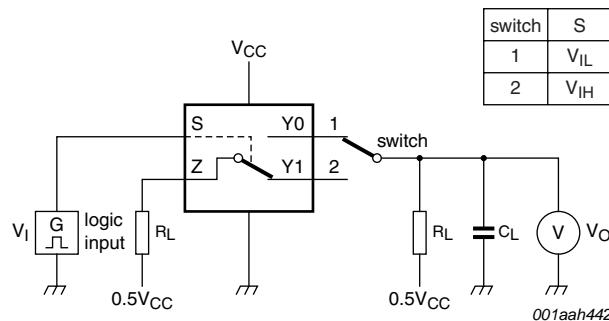
Adjust  $f_i$  voltage to obtain 0 dBm level at output. Increase  $f_i$  frequency until dB meter reads -3 dB.

Fig 19. Test circuit for measuring the frequency response when channel is in ON-state

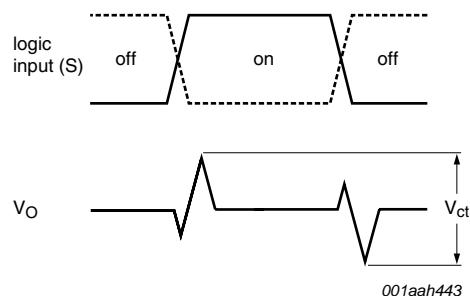


Adjust  $f_i$  voltage to obtain 0 dBm level at input.

Fig 20. Test circuit for measuring isolation (OFF-state)

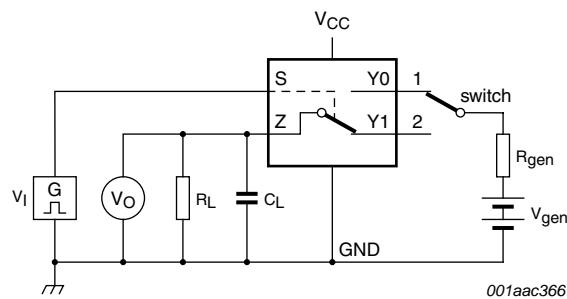


a. Test circuit

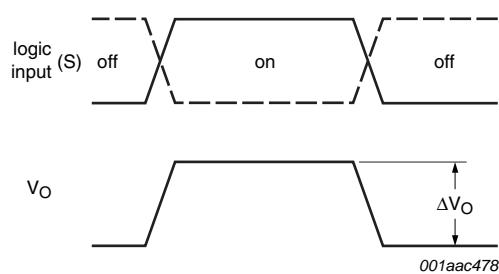


b. Input and output pulse definitions

Fig 21. Test circuit for measuring crosstalk voltage between digital inputs and switch



a. Test circuit



b. Input and output pulse definitions

Definition:  $Q_{inj} = \Delta V_O \times C_L$ .

$\Delta V_O$  = output voltage variation.

$R_{gen}$  = generator resistance.

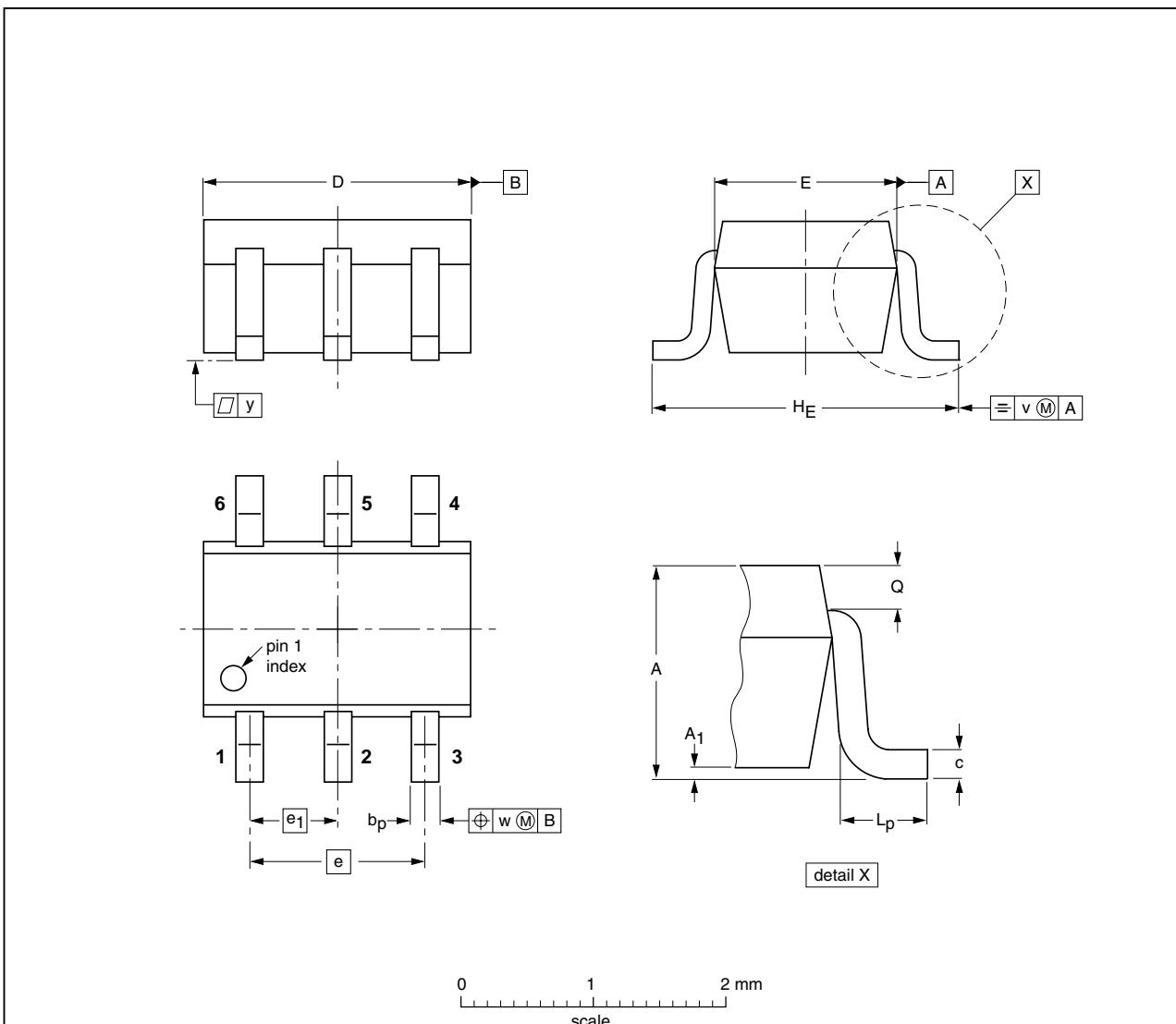
$V_{gen}$  = generator voltage.

Fig 22. Test circuit for measuring charge injection

## 13. Package outline

Plastic surface-mounted package; 6 leads

SOT363



DIMENSIONS (mm are the original dimensions)

UNIT	A	$A_1$ max	$b_p$	c	D	E	e	$e_1$	$H_E$	$L_p$	Q	v	w	y
mm	1.1 0.8	0.1	0.30 0.20	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.25 0.15	0.2	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA	SC-88		
SOT363						-04-11-08- 06-03-16

Fig 23. Package outline SOT363 (SC-88)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886

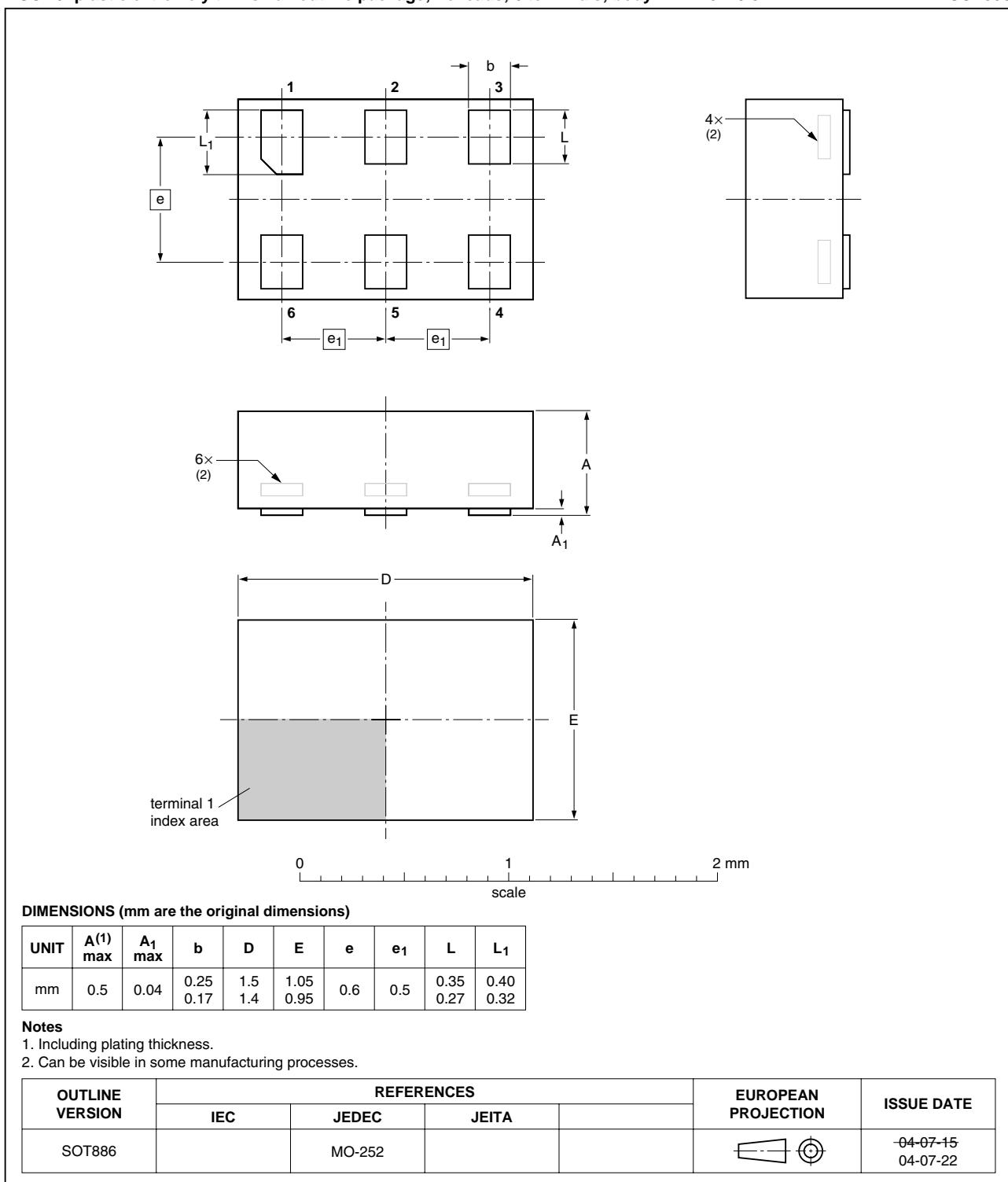


Fig 24. Package outline SOT886 (XSON6)

## 14. Abbreviations

**Table 13. Abbreviations**

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
PDA	Personal Digital Assistant

## 15. Revision history

**Table 14. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3L1T3157_7	20100121	Product data sheet	-	NX3L1T3157_6
Modifications:			<ul style="list-style-type: none"><li>• <a href="#">Section 2</a>: IEC61000-4-2 added.</li><li>• <a href="#">Table 8</a>: ON resistance (flatness) changed at <math>V_{CC} = 4.3</math> V.</li></ul>	
NX3L1T3157_6	20090415	Product data sheet	-	NX3L1T3157_5
NX3L1T3157_5	20080728	Product data sheet	-	NX3L1T3157_4
NX3L1T3157_4	20080718	Product data sheet	-	NX3L1T3157_3
NX3L1T3157_3	20080408	Product data sheet	-	NX3L1T3157_2
NX3L1T3157_2	20080306	Product data sheet	-	NX3L1T3157_1
NX3L1T3157_1	20080103	Product data sheet	-	-

## 16. Legal information

### 16.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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## 18. Contents

<b>1</b>	<b>General description</b>	<b>1</b>
<b>2</b>	<b>Features</b>	<b>1</b>
<b>3</b>	<b>Applications</b>	<b>2</b>
<b>4</b>	<b>Ordering information</b>	<b>2</b>
<b>5</b>	<b>Marking</b>	<b>2</b>
<b>6</b>	<b>Functional diagram</b>	<b>2</b>
<b>7</b>	<b>Pinning information</b>	<b>3</b>
7.1	Pinning	3
7.2	Pin description	3
<b>8</b>	<b>Functional description</b>	<b>3</b>
<b>9</b>	<b>Limiting values</b>	<b>4</b>
<b>10</b>	<b>Recommended operating conditions</b>	<b>4</b>
<b>11</b>	<b>Static characteristics</b>	<b>5</b>
11.1	Test circuits	6
11.2	ON resistance	7
11.3	ON resistance test circuit and graphs	8
<b>12</b>	<b>Dynamic characteristics</b>	<b>10</b>
12.1	Waveform and test circuits	11
12.2	Additional dynamic characteristics	13
12.3	Test circuits	13
<b>13</b>	<b>Package outline</b>	<b>17</b>
<b>14</b>	<b>Abbreviations</b>	<b>19</b>
<b>15</b>	<b>Revision history</b>	<b>19</b>
<b>16</b>	<b>Legal information</b>	<b>20</b>
16.1	Data sheet status	20
16.2	Definitions	20
16.3	Disclaimers	20
16.4	Trademarks	20
<b>17</b>	<b>Contact information</b>	<b>20</b>
<b>18</b>	<b>Contents</b>	<b>21</b>

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Date of release: 21 January 2010

Document identifier: NX3L1T3157\_7